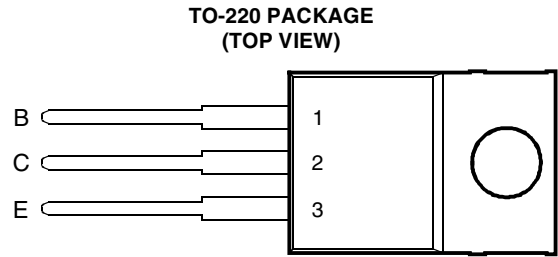


- Rugged Epitaxial Planar Construction
- 10 A Continuous Collector Current
- Operating Characteristics Fully Guaranteed at 100°C
- $t_{xo}$  typically 320 ns,  $I_C = 10$  A



Pin 2 is in electrical contact with the mounting base.

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**absolute maximum ratings at 25°C case temperature (unless otherwise noted)**

RATING		SYMBOL	VALUE	UNIT
Collector-base voltage ( $I_E = 0$ )	TIPL790	$V_{CBO}$	150	V
	TIPL790A		200	
Collector-emitter voltage ( $V_{BE} = 0$ )	TIPL790	$V_{CES}$	150	V
	TIPL790A		200	
Collector-emitter voltage ( $I_B = 0$ )	TIPL790	$V_{CEO}$	120	V
	TIPL790A		150	
Emitter-base voltage		$V_{EBO}$	8	V
Continuous collector current		$I_C$	10	A
Peak collector current (see Note 1)		$I_{CM}$	15	A
Continuous device dissipation at (or below) 25°C case temperature		$P_{tot}$	70	W
Operating junction temperature range		$T_j$	-65 to +150	°C
Storage temperature range		$T_{stg}$	-65 to +150	°C

NOTE 1: This value applies for  $t_p \leq 10$  ms, duty cycle  $\leq 2\%$ .

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**electrical characteristics at 25°C case temperature (unless otherwise noted)**

PARAMETER		TEST CONDITIONS				MIN	TYP	MAX	UNIT
$V_{CEO(sus)}$	Collector-emitter sustaining voltage	$I_C = 100 \text{ mA}$	$L = 25 \text{ mH}$	(see Note 2)	TIPL790 TIPL790A	120 150			V
$V_{CBO}$	Collector-base breakdown voltage	$I_C = 1 \text{ mA}$		(see Note 3)	TIPL790 TIPL790A	150 200			V
$I_{CES}$	Collector-emitter cut-off current	$V_{CE} = 150 \text{ V}$ $V_{CE} = 200 \text{ V}$ $V_{CE} = 150 \text{ V}$ $V_{CE} = 200 \text{ V}$	$V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$	$T_C = 100^\circ\text{C}$ $T_C = 100^\circ\text{C}$	TIPL790 TIPL790A TIPL790 TIPL790A			0.05 0.05 1 1	mA
$I_{CEV}$	Collector cut-off current	$V_{CE} = 150 \text{ V}$ $V_{CE} = 200 \text{ V}$	$1.5 < V_{EB} < 8 \text{ V}$		TIPL790 TIPL790A			50 50	$\mu\text{A}$
$I_{CEO}$	Collector cut-off current	$V_{CE} = 120 \text{ V}$ $V_{CE} = 150 \text{ V}$	$I_B = 0$ $I_B = 0$		TIPL790 TIPL790A			50 50	$\mu\text{A}$
$I_{EBO}$	Emitter cut-off current	$V_{EB} = 5 \text{ V}$	$I_C = 0$					4	mA
$h_{FE}$	Forward current transfer ratio	$V_{CE} = 5 \text{ V}$	$I_C = 0.5 \text{ A}$	(see Notes 3 and 4)		60		500	
$V_{CE(sat)}$	Collector-emitter saturation voltage	$I_B = 20 \text{ mA}$ $I_B = 30 \text{ mA}$ $I_B = 50 \text{ mA}$ $I_B = 50 \text{ mA}$	$I_C = 4 \text{ A}$ $I_C = 7 \text{ A}$ $I_C = 10 \text{ A}$ $I_C = 10 \text{ A}$	(see Notes 3 and 4) $T_C = 100^\circ\text{C}$				1.2 1.5 2.0 2.0	V
$V_{BE(sat)}$	Base-emitter saturation voltage	$I_B = 20 \text{ mA}$ $I_B = 30 \text{ mA}$ $I_B = 50 \text{ mA}$ $I_B = 50 \text{ mA}$	$I_C = 4 \text{ A}$ $I_C = 7 \text{ A}$ $I_C = 10 \text{ A}$ $I_C = 10 \text{ A}$	(see Notes 3 and 4) $T_C = 100^\circ\text{C}$				1.8 1.9 2.2 2.1	V
$V_{EC}$	Parallel diode forward voltage	$I_E = 10 \text{ A}$	$I_B = 0$					3	V
$f_t$	Current gain bandwidth product	$V_{CE} = 10 \text{ V}$	$I_C = 0.5 \text{ A}$	$f = 1 \text{ MHz}$	(see Note 5)		10		MHz
$C_{ob}$	Output capacitance	$V_{CB} = 20 \text{ V}$	$I_E = 0$	$f = 0.1 \text{ MHz}$			90		pF

NOTES: 2. Inductive loop switching measurement.

3. These parameters must be measured using pulse techniques,  $t_p = 300 \mu\text{s}$ , duty cycle  $\leq 2\%$ .

4. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

5. To obtain  $f_t$  the  $[h_{FE}]$  response is extrapolated at the rate of -6 dB per octave from  $f = 1 \text{ MHz}$  to the frequency at which  $[h_{FE}] = 1$ .

**thermal characteristics**

PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			1.79	$^\circ\text{C/W}$

**inductive-load-switching characteristics at 25°C case temperature (unless otherwise noted)**

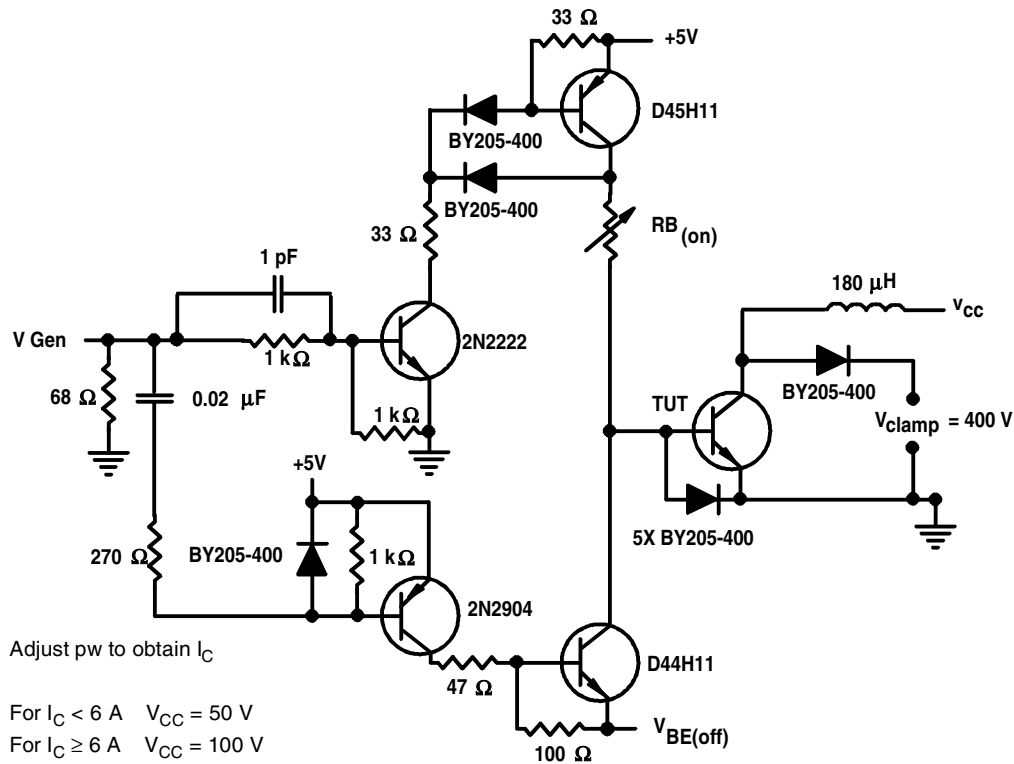
PARAMETER		TEST CONDITIONS †			MIN	TYP	MAX	UNIT
$t_{si}$	Current storage time	$I_C = 10 \text{ A}$ $I_{B(off)} = -2.5 \text{ A}$	$I_{B(on)} = 50 \text{ mA}$ $V_{BE(off)} = -5 \text{ V}$	(see Figures 1 and 2)		450	700	ns
$t_{rv}$	Voltage rise time					160	750	ns
$t_{fi}$	Current fall time					250	400	ns
$t_{ti}$	Current tail time					280	450	ns
$t_{xo}$	Cross over time					320	500	ns

† Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

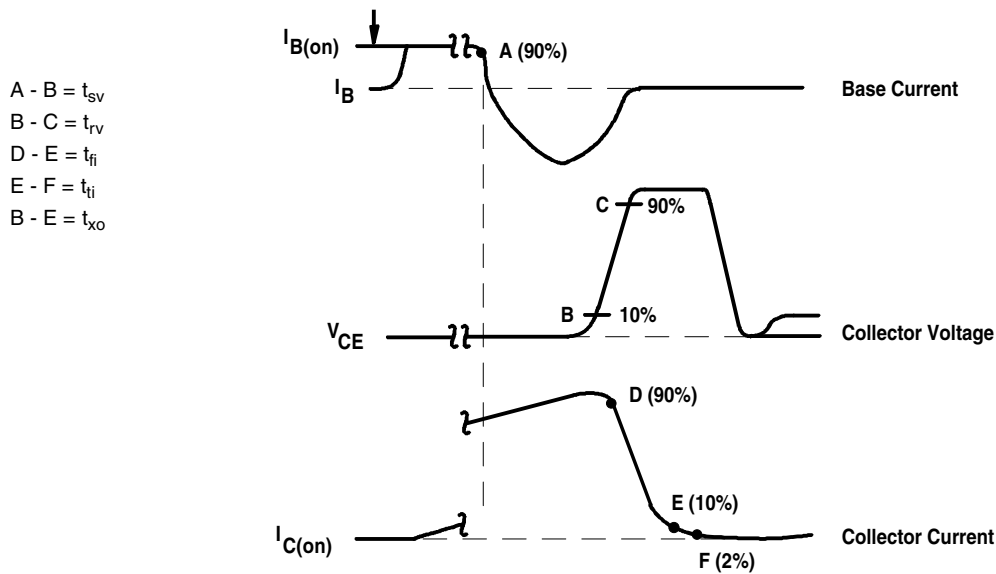
**PRODUCT INFORMATION**

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**PARAMETER MEASUREMENT INFORMATION**



**Figure 1. Inductive-Load Switching Test Circuit**



NOTES: A. Waveforms are monitored on an oscilloscope with the following characteristics:  $t_r < 15 \text{ ns}$ ,  $R_{in} > 10 \Omega$ ,  $C_{in} < 11.5 \text{ pF}$ .  
 B. Resistors must be noninductive types.

**Figure 2. Inductive-Load Switching Waveforms**

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TYPICAL CHARACTERISTICS

TYPICAL DC CURRENT GAIN  
VS  
COLLECTOR CURRENT

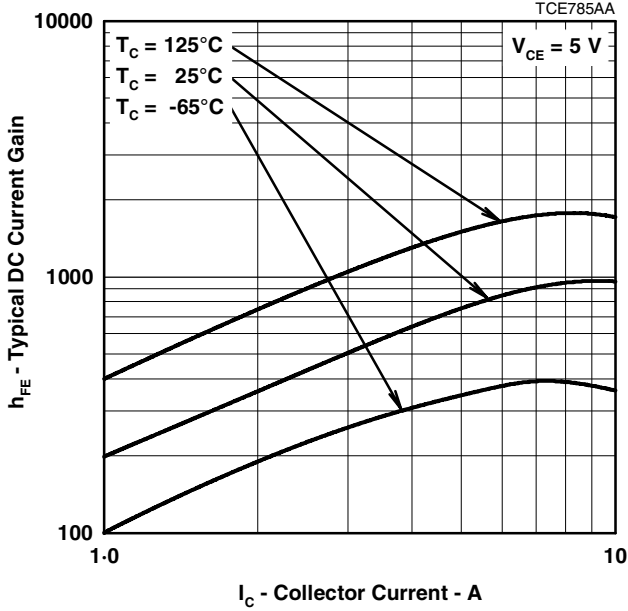


Figure 3.

COLLECTOR-EMITTER SATURATION VOLTAGE  
VS  
BASE CURRENT

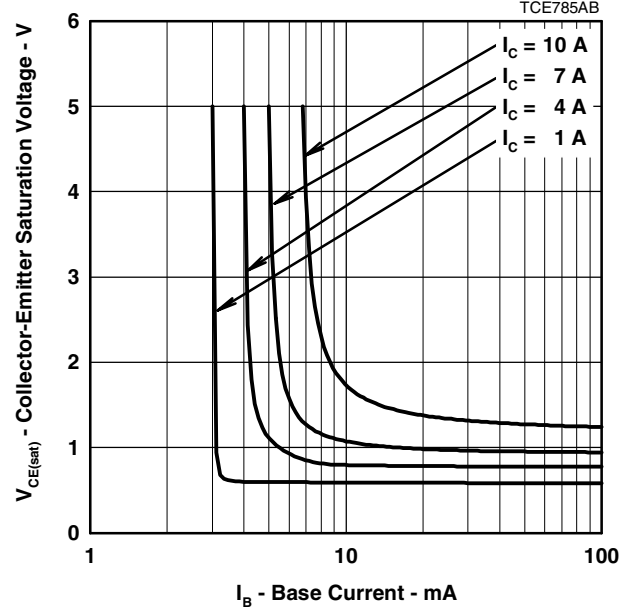


Figure 4.

BASE-EMITTER SATURATION VOLTAGE  
VS  
BASE CURRENT

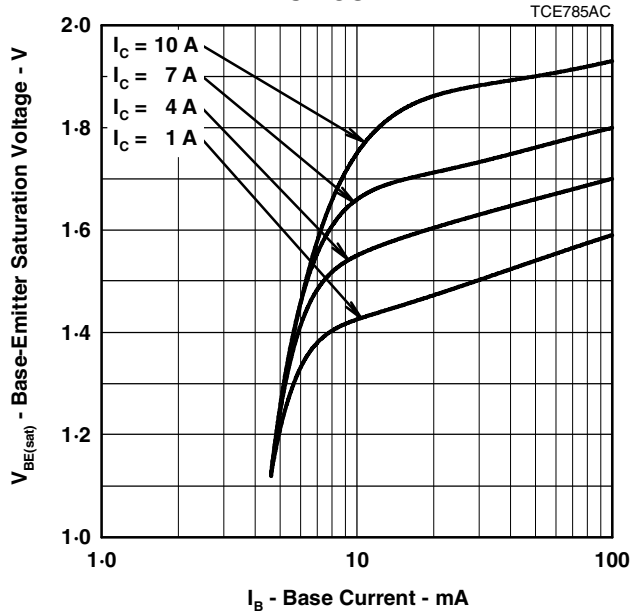


Figure 5.

COLLECTOR CUT-OFF CURRENT  
VS  
CASE TEMPERATURE

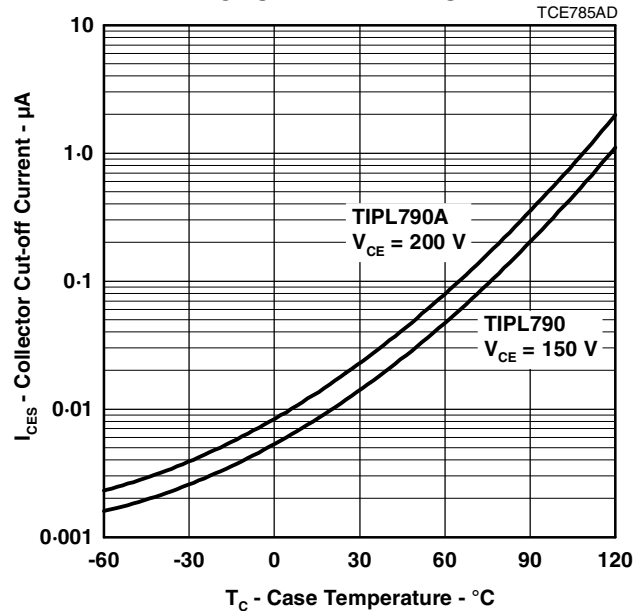
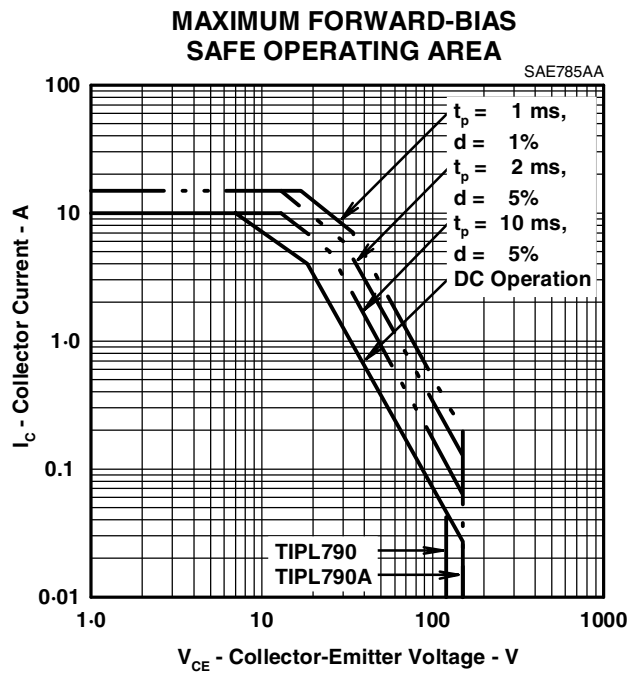


Figure 6.

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**MAXIMUM SAFE OPERATING REGIONS**



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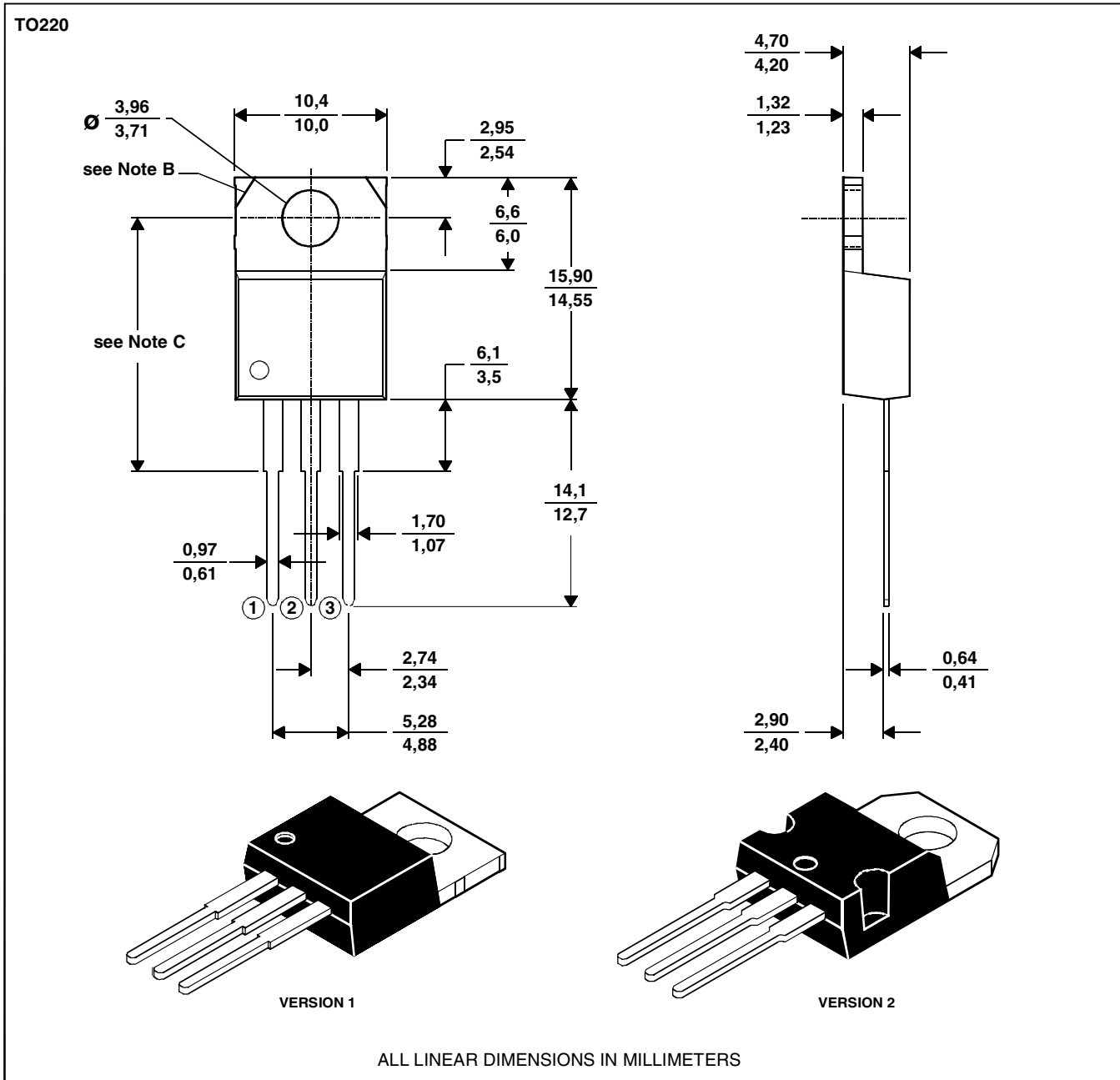
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**MECHANICAL DATA**

**TO-220**

**3-pin plastic flange-mount package**

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTES: A. The centre pin is in electrical contact with the mounting tab.  
 B. Mounting tab corner profile according to package version.  
 C. Typical fixing hole centre stand off height according to package version.  
 Version 1, 18.0 mm. Version 2, 17.6 mm.

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